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March 2003 Revised January 2005

NC7WP00

TinyLogic® ULP Dual 2-Input NAND Gate

General Description

The NC7WP00 is a dual 2-input NAND Gate from Fairchild's Ultra Low Power (ULP) Series of TinyLogic®. Ideal for applications where battery life is critical, this product is designed for ultra low power consumption within the V_{CC} operating range of 0.9V to 3.6V.

The internal circuit is composed of a minimum of inverter stages including the output buffer, to enable ultra low static and dynamic power.

The NC7WP00 is designed for optimized power and speed, and is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining extremely low CMOS power dissipation.

Features

- Space saving US8 package
- Ultra small MicroPak™ Pb-Free package
- 0.9V to 3.6V V_{CC} supply operation
- 3.6V overvoltage tolerant I/O's at V_{CC} from 0.9V to 3.6V

3 ns typ for 3.0V to 3.6V $\rm V_{\rm CC}$

4 ns typ for 2.3V to 2.7V V_{CC}

5 ns typ for 1.65V to 1.95V V_{CC}

6 ns typ for 1.40V to 1.60V V_{CC}

9 ns typ for 1.10V to 1.30V V_{CC}

24 ns typ for 0.90V $V_{\rm CC}$

- Power-Off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL})

±2.6 mA @ 3.00V V_{CC}

±2.1 mA @ 2.30V V_{CC}

±1.5 mA @ 1.65V V_{CC}

±1.0 mA @ 1.40V V_{CC}

 ± 0.5 mA @ 1.10V V_{CC} $\pm 20~\mu A$ @ 0.9V V_{CC}

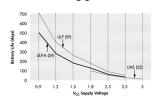
- Low noise switching using design techniques of Quiet Series™ noise/EMI reduction circuitry
- Ultra low dynamic power

Ordering Code:

		Product		
Order Number	Package	Code	Package Description	Supplied As
	Number	Top Mark		
NC7WP00K8X	MAB08A	WP00	8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide	3k Units on Tape and Reel
NC7WP00L8X	MAC08A	Y3	Pb-Free 8-Lead MicroPak. 1.6 mm Wide	5k Units on Tape and Reel

Pb-Free package per JEDEC J-STD-020B.

Battery Life vs. V_{CC} Supply Voltage



TinyLogic ULP and ULP-A with up to 50% less power consumption can extend your battery life significantly. Battery Life = $(V_{battery} *I_{battery} *.9)/(P_{device})/24hrs/day$

Where, $P_{device} = (I_{CC} * V_{CC}) + (C_{PD} + C_L) * V_{CC}^2 * f$

Assumes ideal 3.6V Lithium Ion battery with current rating of 900mAH and derated 90% and device frequency at 10MHz, with C_{L} = 15 pF load

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Logic Symbol

IEEE/IEC



Pin Descriptions

Pin Names	Description
A _n , B _n	Inputs
Y _n	Output

Function Table

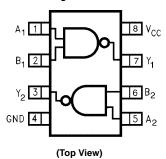
 $\boldsymbol{Y}=\overline{\boldsymbol{AB}}$

Inp	uts	Output		
Α	В	Y		
L	L	Н		
L	Н	Н		
Н	L	Н		
Н	Н	L		

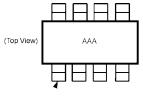
H = HIGH Logic Level L = LOW Logic Level

Connection Diagrams

Pin Assignments for US8



Pin One Orientation Diagram

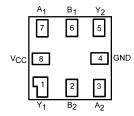


Pin One

AAA represents Product Code Top Mark - see ordering code

Note: Orientation of Top Mark determines Pin One location. Read the top
product code mark left to right, Pin One is the lower left pin (see diagram).

Pad Assignments for MicroPak



(Top Thru View)

Absolute Maximum Ratings(Note 1)

 $\begin{array}{lll} \mbox{Supply Voltage (V$_{CC}$)} & -0.5 \mbox{V to } +4.6 \mbox{V} \\ \mbox{DC Input Voltage (V$_{IN}$)} & -0.5 \mbox{V to } +4.6 \mbox{V} \\ \end{array}$

DC Output Voltage (V_{OUT})

 $\label{eq:VCC} \begin{array}{ll} \mbox{HIGH or LOW State (Note 2)} & -0.5\mbox{V to V}_{CC} + 0.5\mbox{V} \\ \mbox{V}_{CC} = 0\mbox{V} & -0.5\mbox{V to 4.6\mbox{V}} \\ \mbox{DC Input Diode Current (I}_{IK})\mbox{V}_{IN} < 0\mbox{V} & \pm 50\mbox{ mA} \\ \end{array}$

DC Output Diode Current (I_{OK})

 $\begin{array}{lll} \rm V_{OUT} < 0V & -50~mA \\ & \rm V_{OUT} > V_{CC} & \pm 50~mA \\ \\ \rm DC~Output~Source/Sink~Current~(I_{OH}/I_{OL}) & \pm 50~mA \\ \end{array}$

 $\operatorname{DC}\operatorname{V}_{\operatorname{CC}}$ or Ground Current per

Supply Pin (I_{CC} or Ground) \pm 50 mA Storage Temperature Range (T_{STG}) -65° C to +150 $^{\circ}$ C

Recommended Operating Conditions (Note 3)

Supply Voltage 0.9V to 3.6V Input Voltage (V_{IN}) 0V to 3.6V

Output Voltage (V_{OUT})

HIGH or LOW State $$\rm OV\ to\ V_{CC}$$ $V_{CC}=\rm OV$ $\rm OV\ to\ 3.6V$

Output Current in I_{OH}/I_{OL}

 $\begin{array}{lll} \mbox{V}_{CC} = 3.0 \mbox{V to } 3.6 \mbox{V} & \pm 2.6 \mbox{ mA} \\ \mbox{V}_{CC} = 2.3 \mbox{V to } 2.7 \mbox{V} & \pm 2.1 \mbox{ mA} \\ \mbox{V}_{CC} = 1.65 \mbox{V to } 1.95 \mbox{V} & \pm 1.5 \mbox{ mA} \\ \end{array}$

 $\begin{array}{lll} V_{CC} = 1.40 V \ to \ 1.60 V & \pm 1.0 \ mA \\ V_{CC} = 1.10 V \ to \ 1.30 V & \pm 0.5 \ mA \\ V_{CC} = 0.9 V & \pm 20 \ \mu A \end{array}$

Free Air Operating Temperature (T_A) $-40^{\circ}C$ to $+85^{\circ}C$

Minimum Input Edge Rate (Δt/ΔV)

 $V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$ 10 ns/V

Note 1: Absolute Maximum Ratings: are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: IO Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	T _A = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions
Syllibol	Farameter	(V)	Min	Max	Min	Max	Units	Conditions
V_{IH}	HIGH Level	0.90	0.65 x V _{CC}		0.65 x V _{CC}			
	Input Voltage	$1.10 \le V_{CC} \le 1.30$	0.65 x V _{CC}		0.65 x V _{CC}			
		$1.40 \le V_{CC} \le 1.60$	0.65 x V _{CC}		0.65 x V _{CC}		V	
		$1.65 \leq V_{CC} \leq 1.95$	0.65 x V _{CC}		0.65 x V _{CC}		v	
		$2.30 \leq V_{CC} \leq 2.70$	1.6		1.6			
		$3.00 \le V_{CC} \le 3.60$	2.1		2.1			
V_{IL}	LOW Level	0.90		0.35 x V _{CC}		0.35 x V _{CC}		
	Input Voltage	$1.10 \le V_{CC} \le 1.30$		$0.35 \times V_{\rm CC}$		$0.35 \times V_{\rm CC}$		
		$1.40 \le V_{CC} \le 1.60$		$0.35 \times V_{\rm CC}$		$0.35 \times V_{\rm CC}$	V	
		$1.65 \leq V_{CC} \leq 1.95$		$0.35 \times V_{\rm CC}$		$0.35 \times V_{\rm CC}$	v	
		$2.30 \leq V_{CC} \leq 2.70$		0.7		0.7		
		$3.00 \leq V_{CC} \leq 3.60$		0.9		0.9		
V _{OH}	HIGH Level	0.90	V _{CC} - 0.1		V _{CC} - 0.1			
	Output Voltage	$1.10 \le V_{CC} \le 1.30$	V _{CC} - 0.1		V _{CC} - 0.1			
		$1.40 \le V_{CC} \le 1.60$	V _{CC} - 0.1		V _{CC} - 0.1			I _{OH} = -20 μA
		$1.65 \le V_{CC} \le 1.95$	V _{CC} - 0.1		V _{CC} - 0.1			10Η = -20 μΑ
		$2.30 \leq V_{CC} \leq 2.70$	V _{CC} - 0.1		V _{CC} - 0.1			
		$3.00 \leq V_{CC} \leq 3.60$	V _{CC} - 0.1		V _{CC} - 0.1		V	
		$1.10 \le V_{CC} \le 1.30$	0.75 x V _{CC}		0.70 x V _{CC}			$I_{OH} = -0.5 \text{ mA}$
		$1.40 \le V_{CC} \le 1.60$	1.07		0.99			I _{OH} = -1.0 mA
		$1.65 \le V_{CC} \le 1.95$	1.24		1.22			I _{OH} = -1.5 mA
		$2.30 \le V_{CC} \le 2.70$	1.95		1.87			I _{OH} = -2.1 mA
		$3.00 \le V_{CC} \le 3.60$	2.61		2.55			I _{OH} = -2.6 mA

DC Electrical Characteristics (Continued)

Symbol	Parameter	V _{CC}	T _A =	+25°C	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions
Oymboi	i diametei	(V)	Min	Max	Min	Max	Oilles	Conditions
V _{OL}	LOW Level	0.90		0.1		0.1		
	Output Voltage	$1.10 \leq V_{CC} \leq 1.30$		0.1		0.1		
		$1.40 \leq V_{CC} \leq 1.60$		0.1		0.1		I - 20 A
		$1.65 \leq V_{CC} \leq 1.95$		0.1		0.1		$I_{OL} = 20 \mu A$
		$2.30 \leq V_{CC} \leq 2.70$		0.1		0.1		
		$3.00 \leq V_{CC} \leq 3.60$		0.1		0.1	V	
		$1.10 \le V_{CC} \le 1.30$		0.30 x V _{CC}		0.30 x V _{CC}		I _{OL} = 0.5 mA
		$1.40 \le V_{CC} \le 1.60$		0.31		0.37		I _{OL} = 1.0 mA
		$1.65 \leq V_{CC} \leq 1.95$		0.31		0.35		I _{OL} = 1.5 mA
		$2.30 \leq V_{CC} \leq 2.70$		0.31		0.33		I _{OL} = 2.1 mA
		$3.00 \leq V_{CC} \leq 3.60$		0.31		0.33		I _{OL} = 2.6 mA
I _{IN}	Input Leakage Current	0.90 to 3.60		±0.1		±0.5	μΑ	$0 \le V_I \le 3.6V$
I _{OFF}	Power Off Leakage Current	0		0.5		0.5	μΑ	$0 \le (V_I, V_O) \le 3.6V$
I _{CC}	Quiescent Supply Current	0.90 to 3.60		0.9		0.9	μΑ	$V_I = V_{CC}$ or GND

AC Electrical Characteristics

Symbol	Parameter	v _{cc}		T _A = +25°C	;	$T_A = -40^{\circ}$	C to +85°C	Units	Conditions	Figure
Syllibol	Parameter	(V)	Min	Тур	Max	Min Max		Units	Conditions	Number
t _{THL} ,	Propagation Delay	0.90		24.0						
t _{PLH}		$1.10 \leq V_{CC} \leq 1.30$	4.0	9.0	19.0	3.5	31.0			
		$1.40 \leq V_{CC} \leq 1.60$	2.0	6.0	12.0	1.5	14.0	ns	C _L = 10 pF	Figures
		$1.65 \leq V_{CC} \leq 1.95$	1.5	5.0	10.0	1.0	12.0	115	$R_L = 1 M\Omega$	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.0	4.0	7.0	0.8	8.0			
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3.0	6.0	0.5	7.0			
t _{PHL} ,	Propagation Delay	0.90		27.0						
t _{PLH}		$1.10 \leq V_{CC} \leq 1.30$	5.0	10.0	20.0	4.5	34.0			
		$1.40 \leq V_{CC} \leq 1.60$	3.0	7.0	13.0	2.5	16.0	ns	C _L = 15 pF	Figures 1, 2
		$1.65 \leq V_{CC} \leq 1.95$	2.0	5.0	10.0	2.0	12.0	115	$R_L = 1 M\Omega$	
		$2.30 \leq V_{CC} \leq 2.70$	1.5	4.0	7.0	1.0	8.0			
		$3.00 \leq V_{CC} \leq 3.60$	1.0	3.0	6.0	0.5	7.0			
t _{PHL}	Propagation Delay	0.90		34.0						
t _{PLH}		$1.10 \leq V_{CC} \leq 1.30$	6.0	12.0	24.0	5.0	43.0			
		$1.40 \leq V_{CC} \leq 1.60$	4.0	8.0	16.0	3.0	18.0	ns	C _L = 30 pF	Figures
		$1.65 \leq V_{CC} \leq 1.95$	2.0	6.0	12.0	2.0	14.0	113	$R_L = 1 M\Omega$	1, 2
		$2.30 \leq V_{CC} \leq 2.70$	1.0	5.0	9.0	1.0	10.0			
		$3.00 \leq V_{CC} \leq 3.60$	0.8	4.0	7.0	0.5	9.0			
C _{IN}	Input Capacitance	0		2.0				pF		
C _{OUT}	Output Capacitance	0		4.0				pF		
C _{PD}	Power Dissipation Capacitance	0.9 to 3.60		6.0				pF	$V_I = 0V \text{ or } V_{CC},$ f = 10 MHz	

AC Loading and Waveforms

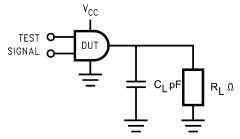


FIGURE 1. AC Test Circuit

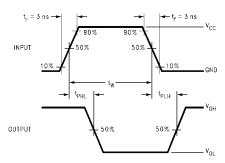


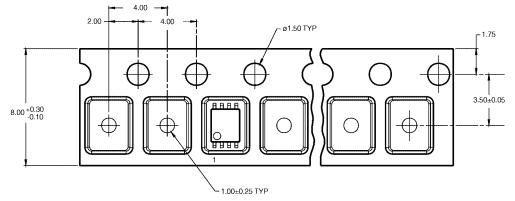
FIGURE 2. AC Waveforms

	Symbol	V _{CC}								
	Cymbol	$3.3V \pm 0.3V$	$\textbf{2.5V} \pm \textbf{0.2V}$	$\textbf{1.8V} \pm \textbf{0.15V}$	$1.5V \pm 0.10V$	$1.2V \pm 0.10V$	0.9V			
Γ	V_{mi}	1.5V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2			
Π	V _{mo}	1.5V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2			

Tape and Reel Specification TAPE FORMAT for US8

Package	Tape	Number	Cavity	Cover Tape	
Designator	Section	Cavities	Status	Status	
	Leader (Start End)	125 (typ)	Empty	Sealed	
K8X	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (typ)	Empty	Sealed	

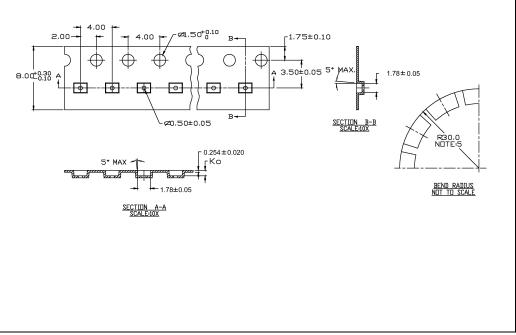
TAPE DIMENSIONS inches (millimeters)



TAPE FORMAT for MicroPak

Package	Таре	Number	Cavity	Cover Tape
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
L8X	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

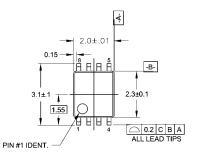
TAPE DIMENSIONS inches (millimeters)

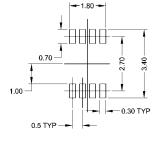


Tape and Reel Specification (Continued) REEL DIMENSIONS inches (millimeters) TAPE SLOT DETAIL X SCALE: 3X W₃ W₂

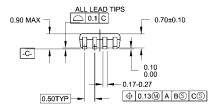
Tape Size	A	В	С	D	N	W1	W2	W3
0 mm	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/-0.000	0.567	W1 + 0.078/-0.039
8 mm	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50/-0.00)	(14.40)	(W1 + 2.00/-1.00)

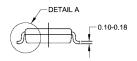
Physical Dimensions inches (millimeters) unless otherwise noted

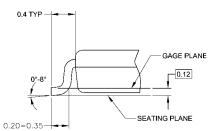




LAND PATTERN RECOMMENDATION







NOTES:

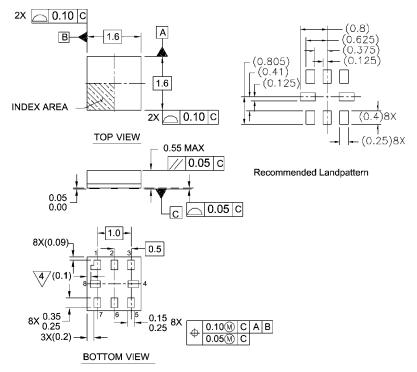
- A. CONFORMS TO JEDEC REGISTRATION MO-187
 B. DIMENSIONS ARE IN MILLIMETERS.
 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

DETAIL A

MAB08AREVC

8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide Package Number MAB08A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Notes:

- 1. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y.14M-1994
- 4/PIN 1 FLAG, END OF PACKAGE OFFSET.

MAC08AREVC

Pb-Free 8-Lead MicroPak, 1.6 mm Wide Package Number MAC08A

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